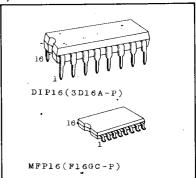
# C2MOS DIGITAL INTEGRATED CIRCUIT TC4049BP/BF, TC4050BP/BF

TC4049BP/TC4049BF HEX BUFFER/CONVERTER (Inverting Type) TC4050BP/TC4050BF HEX BUFFER/CONVERTER (Non-Inverting Type)

TC4049BP/BF, TC4050BP/BF contain six circuits of buffers. TC4049BP/BF is inverter type and TC4050BP/BF is non-inverter type.

Since one TTL or DTL can be directly driven having large output current, these are useful for interfacing from CMOS to TTL or DTL. As voltage up to  $V_{\rm SS}$  +18 volts can be applied to the input regardless of VDD, these can be also used as the level converter IC's which converts CMOS logical circuits of 15 volts or 10 volts system to CMOS/TTL logical circuits of 5 volts system.

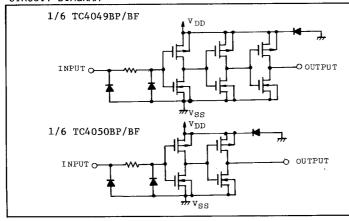
Ideal switching characteristic has been obtained by the circuit diagram of three stage inverters for TC4049BP/ BF and two stage inverters for TC4050BP/BF.

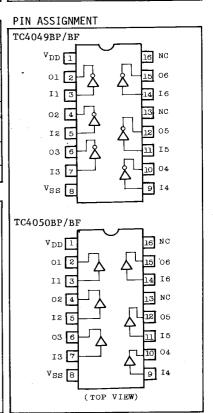


#### ABSOLUTE MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	UNITS
DC Supply Voltage	$\Lambda^{\mathrm{DD}}$	$V_{SS}-0.5 \sim V_{SS}+20$	V
Input Voltage	VIN	$V_{SS}$ -0.5 $\sim V_{SS}$ +20	v
Output Voltage	VOUT	$V_{SS}$ -0.5 $\sim V_{DD}$ +0.5	V
DC Input Voltage	IIN	10	mA
Power Dissipation	PD	300(DIP)/180(MFP)	mW
Operating Temperature Range	TA	<b>-</b> 40 ∼ 85	. °C
Storage Temperature Range	T <sub>stg</sub>	-65 ∿ 150	°C
Lead Temp./Time	T <sub>sol</sub>	260°C • 10 sec	

### CIRCUIT DIAGRAM





## RECOMMENDED OPERATING CONDITIONS ( $v_{SS}=ov$ )

CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNITS
DC Supply Voltage	$v_{DD}$	3	-	18	v
Input Voltage	VIN	0	_	18	v

## STATIC ELECTRICAL CHARACTERISTICS (VSS=0V)

CHARACTERISTIC	SYMBOL	TEST CONDITIONS	V <sub>DD</sub> (V)	-40	-40°C		25°C			85°C	
CHARACTERISTIC		TEST CONDITIONS		MIN.	MAX.	MIN.	TYP.	MAX.	MIN.	MAX.	UNITS
High-Level Output Voltage		I <sub>OUT</sub>  <1 <sub>μ</sub> A V <sub>IN</sub> =V <sub>SS</sub> , V <sub>DD</sub>	5 10 15	4.95 9.95 14.95	-	9.9	5.00 10.00 15.00	-	4.95 9.95 14.95	-	
Low-Level Output Voltage	v <sub>OL</sub>	I <sub>OUT</sub>  <1μΑ V <sub>IN</sub> =V <sub>SS</sub> , V <sub>DD</sub>	5 10 15	- - -	0.05 0.05 0.05	-	0.00 0.00 0.00	0.05 0.05 0.05	_	0.05 0.05 0.05	v
Output High Current	I <sub>OH</sub>	V <sub>OH</sub> =4.6V V <sub>OH</sub> =2.5V V <sub>OH</sub> =9.5V V <sub>OH</sub> =13.5V V <sub>IN</sub> =V <sub>SS</sub> , V <sub>DD</sub>	5 10	-0.73 -2.4 -1.8 -4.8	- - - -	-0.65 -2.1 -1.65 -4.3	-2.5	- - -	-0.58 -1.9 -1.35 -3.5	-	mA
Output Low Current	I <sub>OL</sub>	V <sub>OL</sub> =0.4V V <sub>OL</sub> =0.5V V <sub>OL</sub> =1.5V V <sub>IN</sub> =V <sub>SS</sub> , V <sub>DD</sub>	5 10 15	3.8 9.6 25.0	- -	3.2 8.0 24.0	6.4 16 48	- - -	2.9 6.6 20.0	1 1 1	IIIA
Input High Voltage VIH VOUT=1.0V,9. VOUT=1.5V,13		V <sub>OUT</sub> =0.5V,4.5V V <sub>OUT</sub> =1.0V,9.0V V <sub>OUT</sub> =1.5V,135V   I <sub>OUT</sub>   < 1µA	5 10 15	3.5 7.0 11.0	-	3.5 7.0 11.0	2.75 5.5 8.25		3.5 7.0 11.0	- - -	
Input Low Voltage	VIL	V <sub>OUT</sub> =0.5V,4.5V V <sub>OUT</sub> =1.0V,9.0V V <sub>OUT</sub> =1.5V,135V   I <sub>OUT</sub>  <1µA	5 10 15	-	1.5 3.0 4.0	- - -	2.25 4.5 6.75	1.5 3.0 4.0	- -	1.5 3.0 4.0	V
Input "H" Level Corrent "L"	I <sub>IH</sub>	V <sub>IH</sub> =18V	18		0.1	-	10-5	0.1		1.0	μA
Level	IIL	V <sub>IL</sub> =0V	18	-	-0.1		-10 <sup>-5</sup>	-0.1		-1.0	
Quiescent Device Current	I <sub>DD</sub>	V <sub>IN</sub> =V <sub>SS</sub> , V <sub>DD</sub>	5 10 15	-	1 2 4	-	0.002 0.004 0.008	1 2 4	- - -	30 60 120	Aμ

<sup>\*</sup> All valid input combinations.

DYNAMIC ELECTRICAL CHARACTERISTICS (Ta=25°C,  $v_{SS}$ =0v,  $c_L$ =50pF)

	CHARACTERISTIC	SYMBOL	TEST CONDITION	V <sub>DD</sub> (V)	MIN.	TYP.	MAX	UNITS
Output Transition Time (Low to High)		tTLH		5 10	-	60 30	160 80	
(20)	Low to mign,			15	_	25	60	
Outr	out Transition Time			5	_	20	60	
1 '	gh to Low)	t <sub>THL</sub>		10	_	10	40	
\	<b>,</b> ,			15		8	30	
	Propagation Delay Time (Low to High) Propagation Delay Time (High to Low)			5	_	60	120	
BF		tpLH		10	-	35	65	ns
IP/1				15		30	50	
49E				5	_	40	60	
Propagation Delay Time (High to Low)	, , ,	tpHL		10	_	20	30	
	'		15	-	15	20		
Er.	Propagation Delay			5	_	50	130	
		t <sub>pLH</sub>		10	_	30	70	
	Time (Low to High)			15		25	55	
) 50	Propagation Delay Time (High to Low)			5	-	30	70	
TC4		tpHL		10	-	17	35	
	Time (HIEH CO DOW)			15	-	14	25	
In	Input Capacitance			•	_	5	7.5	pF

#### WAVEFORM FOR MEASUREMENT OF DYNAMIC CHARACTERISTICS

